



# KA5Q0740RT

## Fairchild Power Switch(FPS)

### Features

- Quasi Resonant Converter Controller
- Internal Burst Mode Controller for Stand-by Mode
- Pulse by Pulse Current Limiting
- Over Current Latch Protection
- Over Voltage Protection (Vsync: Min. 11V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

### Description

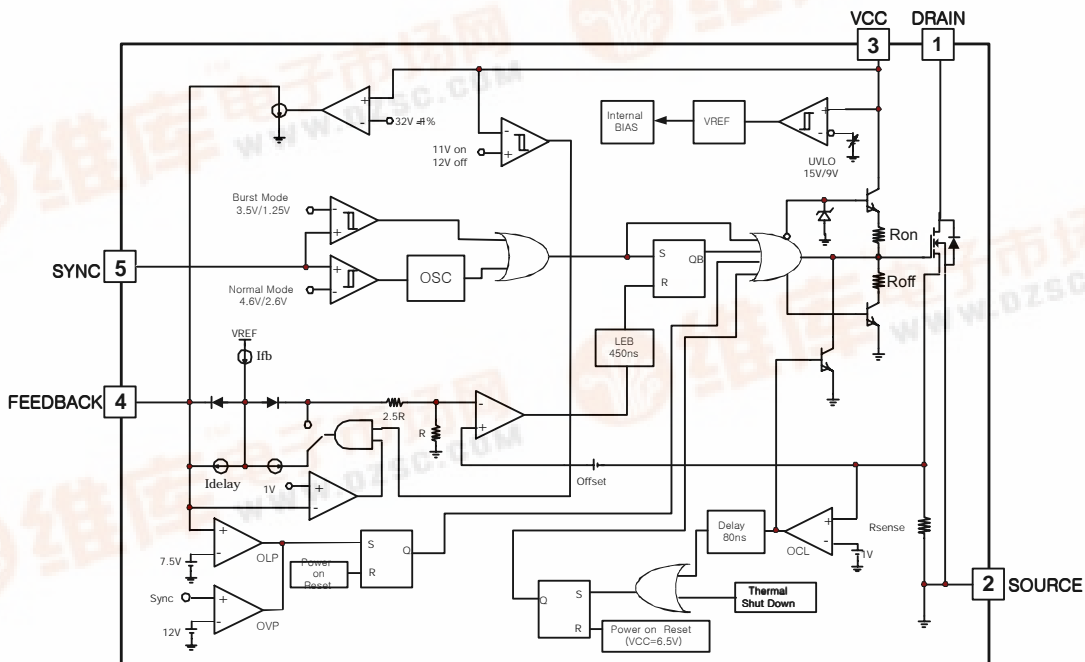
The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and a current mode PWM IC. The integrated PWM controller includes the fixed oscillator, the under voltage lock out, the leading edge blanking, the optimized gate turn-on/turn-off driver, the thermal shut down protection, the over voltage protection, and the temperature compensated precision current sources for loop compensation and fault protection circuitry. Compared to a discrete MOSFET and a controller or a RCC switching converter solutions, a Fairchild Power Switch(FPS) can reduce the total number of components, design size, and weight, so it will improve efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective design in a quasi-resonant converter as a C-TV power supply.

TO-220F-5L



1. Drain
2. GND
3. VCC
4. Feedback
5. Sync

### Internal Block Diagram



## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Gate Voltage (RGS=1MΩ)	VDGR	400	V
Gate-Source (GND) Voltage	VGS	±30	V
Drain Current Pulsed <sup>(2)</sup>	IDM	18.4	ADC
Single Pulsed Avalanch Current <sup>(3)</sup> (Energy <sup>(2)</sup> )	IAS(EAS)	20(360)	A(mJ)
Continuous Drain Current (Tc = 25°C)	ID	4.6	ADC
Continuous Drain Current (TC=100°C)	ID	2.9	ADC
Supply Voltage	VCC	40	V
Analog Input Voltage Range	Vsync	-0.3 to 13V	V
	VFB	-0.3 to VCC	V
Total Power Dissipation	PD	42	W
	Derating	0.33	W/°C
Operating Junction Temperature	TJ	+160	°C
Operating Ambient Temperature	TA	-25 to +85	°C
Storage Temperature Range	TSTG	-55 to +150	°C
Thermal Resistance	Rthjc	2.98	°C/W

### Notes:

1. Tj = 25°C to 150°C
2. Repetitive rating: Pulse width limited by maximum junction temperature
3. L = 30mH, VDD = 50V, RG = 25Ω, starting Tj = 25°C
4. L = 13uH, starting Tj = 25°C

## Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BVDSS	VGS = 0V, ID = 50μA	400	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS = Max, Rating, VGS = 0V	-	-	200	μA
		VDS = 0.8*Max., Rating VGS = 0V, TC = 85°C	-	-	300	μA
Static Drain-source on Resistance <sup>(Note)</sup>	RDS(ON)	VGS = 10V, ID = 2.3A	-	0.9	1.1	Ω
Input Capacitance	Ciss	VGS = 0V, VDS = 25V, f = 1MHz	-	710	-	pF
Output Capacitance	Coss		-	90	-	
Reverse Transfer Capacitance	Crss		-	10	-	
Turn on Delay Time	td(on)	VDD = 0.5BVDSS, ID = 7.0A (MOSFET switching time are essentially independent of operating temperature)	-	15	-	nS
Rise Time	tr		-	55	-	
Turn Off Delay Time	td(off)		-	55	-	
Fall Time	tf		-	50	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS = 10V, ID = 7.0A, VDS = 0.5B VDS (MOSFET Switching time are Essentially independent of operating temperature)	-	20	26	nC
Gate-Source Charge	Qgs		-	4.0	-	
Gate-Drain (Miller) Charge	Qgd		-	7.3	-	

### Note:

1. Pulse test : Pulse width ≤ 300μS, duty ≤ 2%

**Electrical Characteristics** (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>UVLO SECTION</b>						
Start Threshold Voltage	VSTART	VFB = GND	14	15	16	V
Stop Threshold Voltage	VSTOP	VFB = GND	8	9	10	V
<b>OSCILLATOR SECTION</b>						
Initial Frequency	FOSC	-	18	20	22	kHz
Voltage Stability	FSTABLE	12V ≤ Vcc ≤ 23V	0	1	3	%
Temperature Stability (Note2)	ΔFOSC	-25°C ≤ Ta ≤ 85°C	0	±5	±10	%
Maximum Duty Cycle	DMAX	-	92	95	98	%
Minimum Duty Cycle	DMIN	-	-	-	0	%
<b>FEEDBACK SECTION</b>						
Feedback Source Current	IFB	VFB = GND	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	VSD	Vfb ≥ 6.9V	6.9	7.5	8.1	V
Shutdown Delay Current	IDELAY	VFB = 5V	4	5	6	μA
<b>PROTECTION SECTION</b>						
Over Voltage Protection	VOVP	Vsync ≥ 11V	11	12	13	V
Over Current Latch Voltage (Note2)	VOCL	-	0.9	1.0	1.1	V
Thermal Shutdown Temp.	TSD	-	140	160	-	°C

**Note:**

1. These parameters is the current flowing in the Control IC.
2. These parameters, although guaranteed, are tested in EDS(wafer test) process.
3. These parameters indicate Inductor Current.

**Electrical Characteristics** (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>SYNC SECTION</b>						
Normal Sync High Threshold Voltage	VNSH	Vcc = 16V, Vfb = 5V	4.0	4.6	5.2	V
Normal Sync Low Threshold Voltage	VNSL	Vcc = 16V, Vfb = 5V	2.3	2.6	2.9	V
Burst Sync High Threshold Voltage	VBSH	Vcc = 10.5V, Vfb = 0V	3.2	3.6	4.0	V
Burst Sync Low Threshold Voltage	VBSL	Vcc = 10.5V, Vfb = 0V	1.1	1.3	1.5	V
<b>BURST MODE SECTION</b>						
Burst mode Low Threshold Voltage	VBURL	Vfb = 0V	10.4	11.0	11.6	V
Burst mode High Threshold Voltage	VBURH	Vfb = 0V	11.4	12.0	12.6	V
Burst mode Enable Feedback Voltage	VBEN	Vcc = 10.5V	0.7	1.0	1.3	V
Burst mode Peak Current Limit	IBU_PK	Vcc = 10.5V	0.65	0.85	1.1	A
<b>PRIMARY SIDE REGULATION SECTION</b>						
Primary Regulation Threshold Voltage	VPR	I <sub>fb</sub> = 700uA, Vfb = 4V	32.0	32.5	33.0	V
Primary Regulation Transconductance	GPR	-	2.0	2.6	-	mA/V
<b>CURRENT LIMIT(SELF-PROTECTION)SECTION</b>						
Peak Current Limit(Note3)	IPK	-	4.4	5.0	5.6	A
<b>TOTAL DEVICE SECTION</b>						
Start Up Current	I <sub>START</sub>	Vfb = GND, V <sub>CC</sub> = 14V	-	0.1	0.2	mA
Operating Supply Current (Note1)	I <sub>OP</sub>	Vfb = GND, V <sub>CC</sub> = 16V	-	10	18	mA
	I <sub>OP(MIN)</sub>	Vfb = GND, V <sub>CC</sub> = 10V				
	I <sub>OP(MAX)</sub>	Vfb = GND, V <sub>CC</sub> = 28V				

**Note:**

1. These parameters is the current flowing in the Control IC.
2. These parameters, although guaranteed, are tested in EDS(wafer test) process.
3. These parameters indicate Inductor Current.

## Typical Performance Characteristics

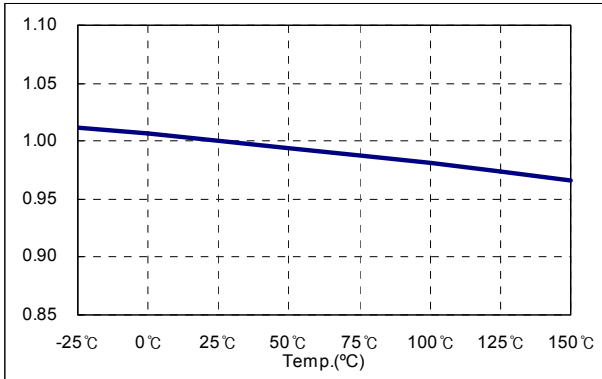


Figure 1. Start Voltage

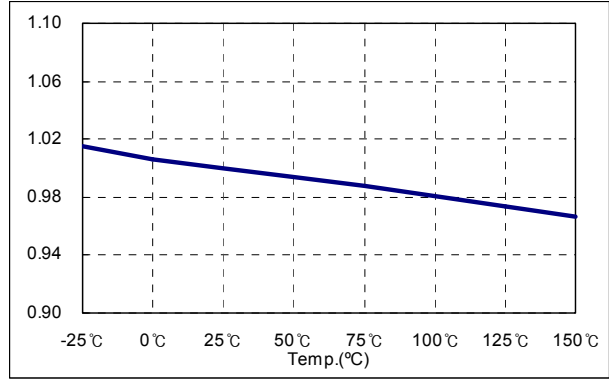


Figure 2. Stop Voltage

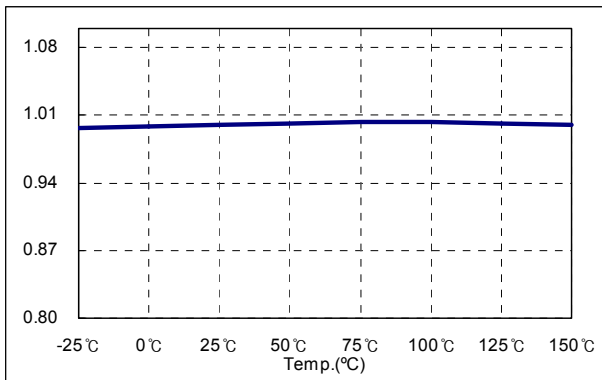


Figure 3. Stand by Current

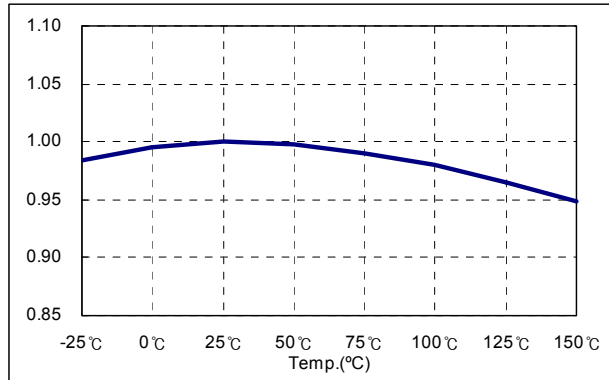


Figure 4. Operating Current

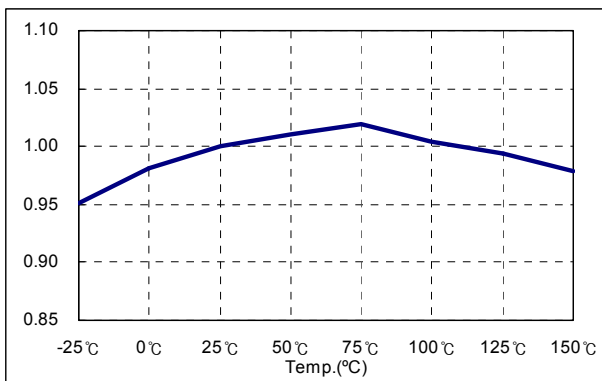


Figure 5. Initial Frequency

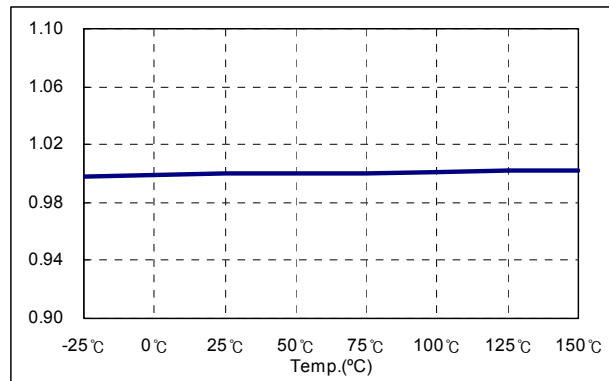


Figure 6. Maximum Duty

## Typical Performance Characteristics (Continued)

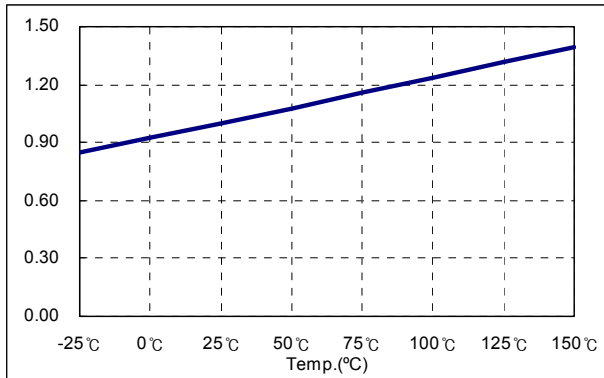


Figure 7. Feedback Offset Voltage

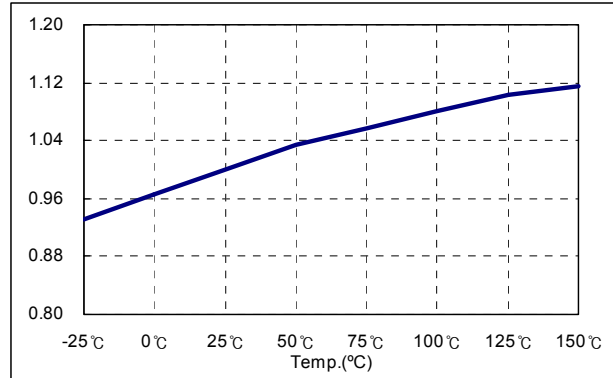


Figure 8. Feedback Source Current

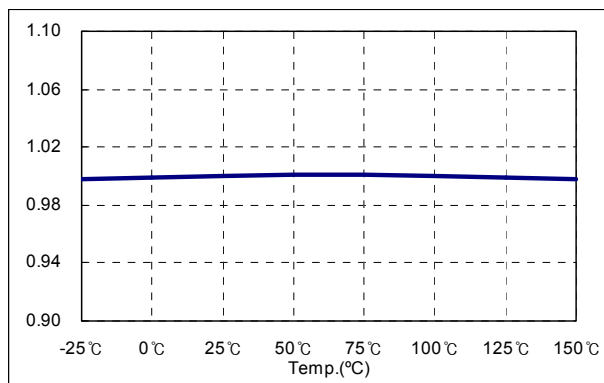


Figure 9. Over Voltage Protection

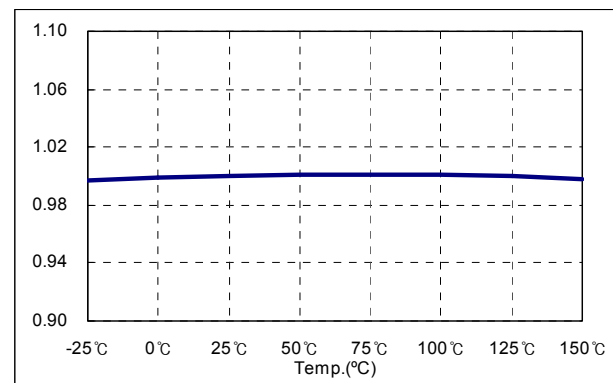


Figure 10. Shutdown Feedback Voltage

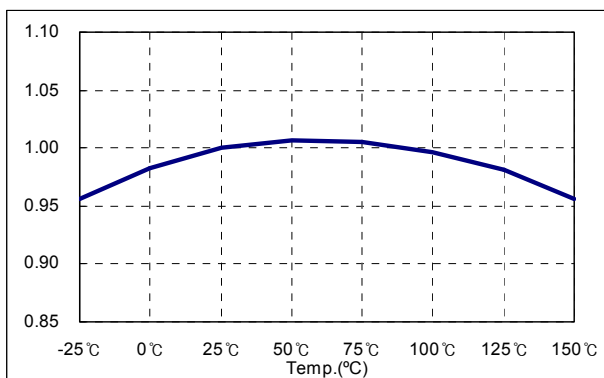


Figure 11. ShutDown Delay Current

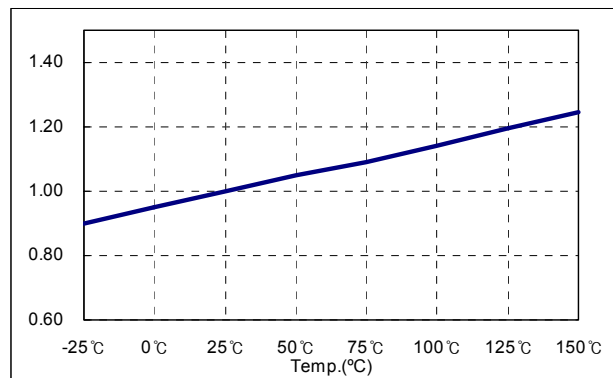
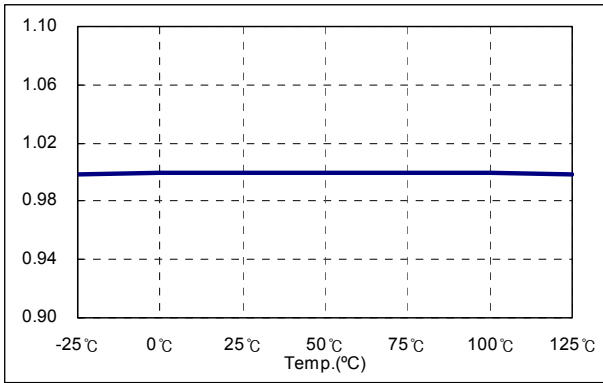
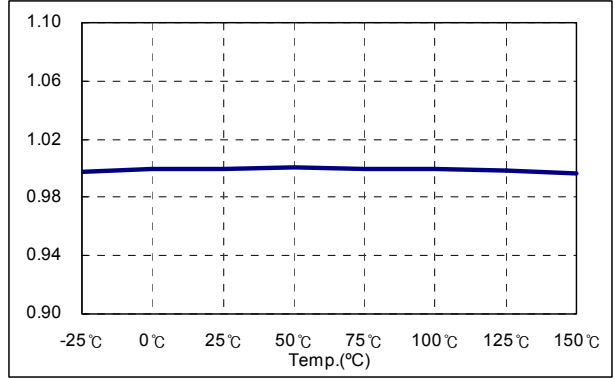


Figure 12. Burst Mode Enable Feedback Voltage

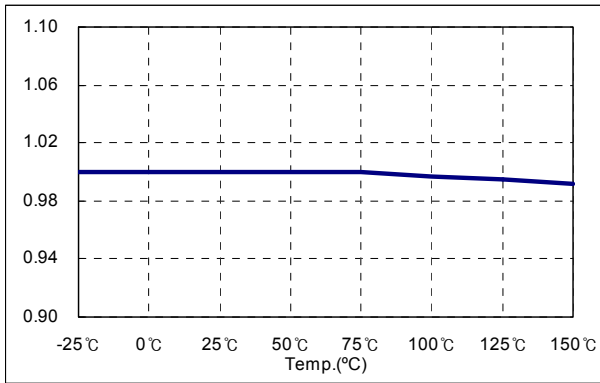
**Typical Performance Characteristics** (Continued)



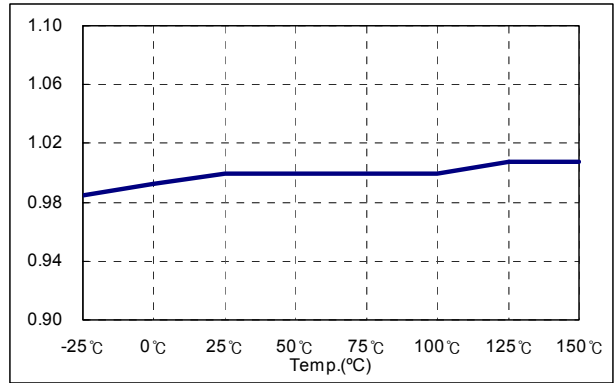
**Figure 13. Burst Mode Low Threshold Voltage**



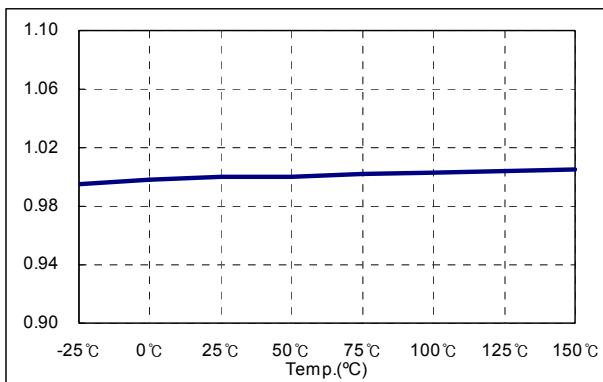
**Figure 14. Burst Mode High Threshold Voltage**



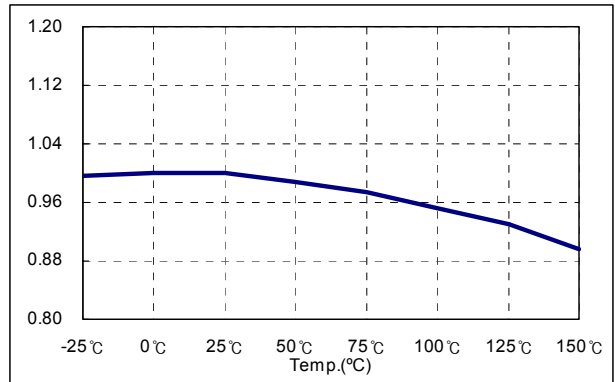
**Figure 15. Burst Mode Sync. High Threshold Voltage**



**Figure 16. Burst Mode Sync. Low Threshold Voltage**



**Figure 17. Primary Voltage**



**Figure 18. Primary Mode Gain**



Typical Performance Characteristics (Continued)

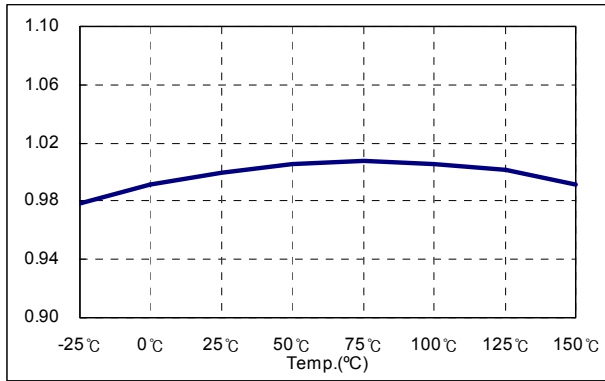


Figure 19. Peak Current Limit

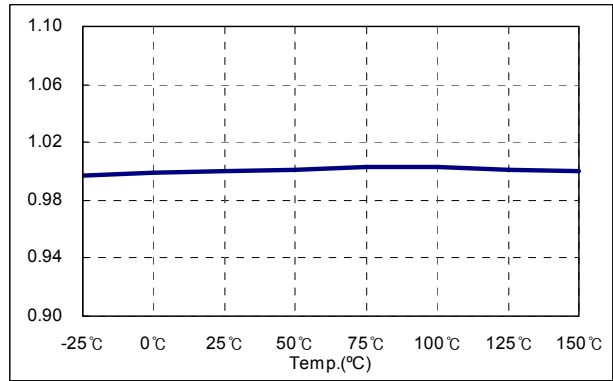


Figure 20. Burst Mode Peak Current Limit

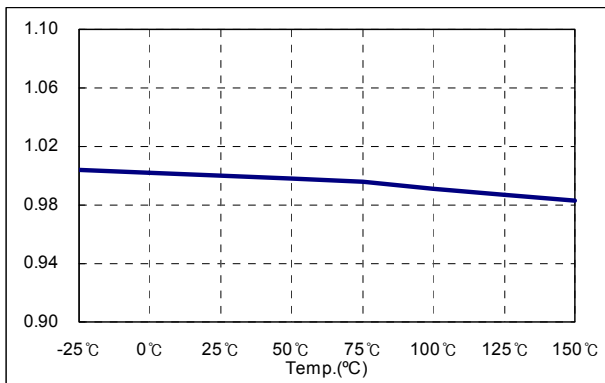


Figure 21. Normal Mode Sync. High Threshold Voltage

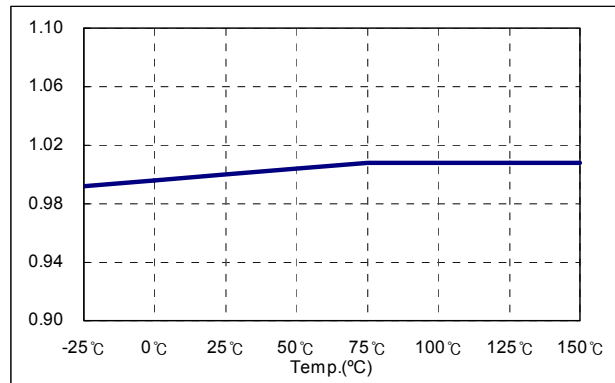


Figure 21. Normal Mode Sync. Low Threshold Voltage

Typical Performance Characteristics(MOSFET Part)

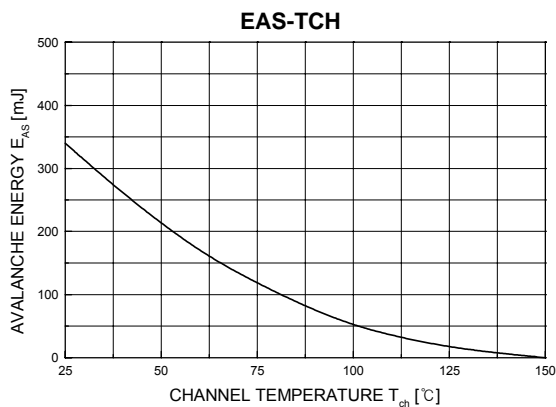


Figure 22. Temperature (T<sub>C</sub>) vs. Eas Curve

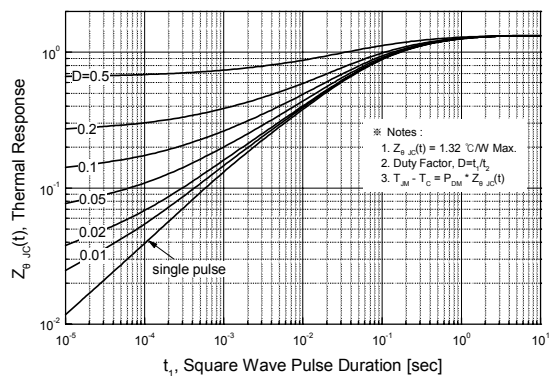
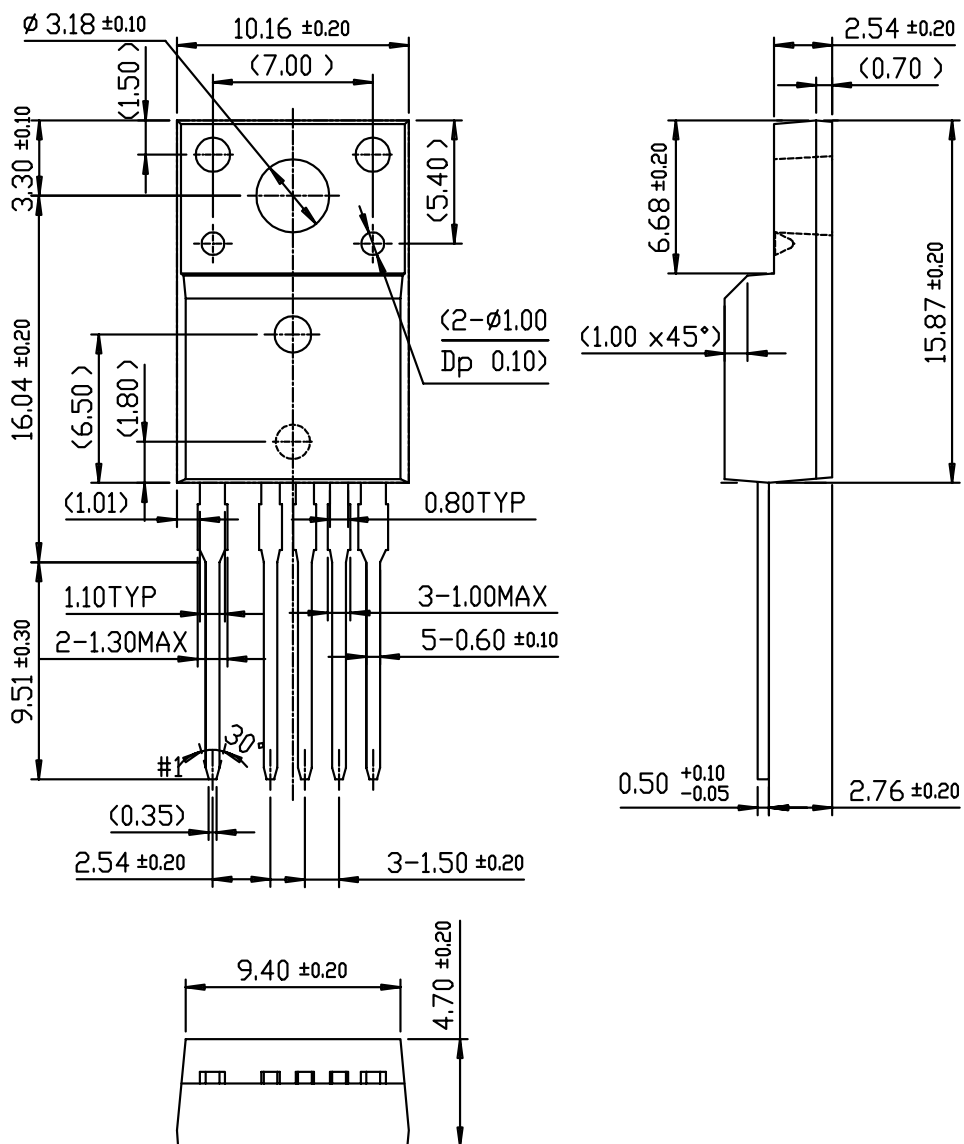


Figure 23. Transient Thermal Response Curve

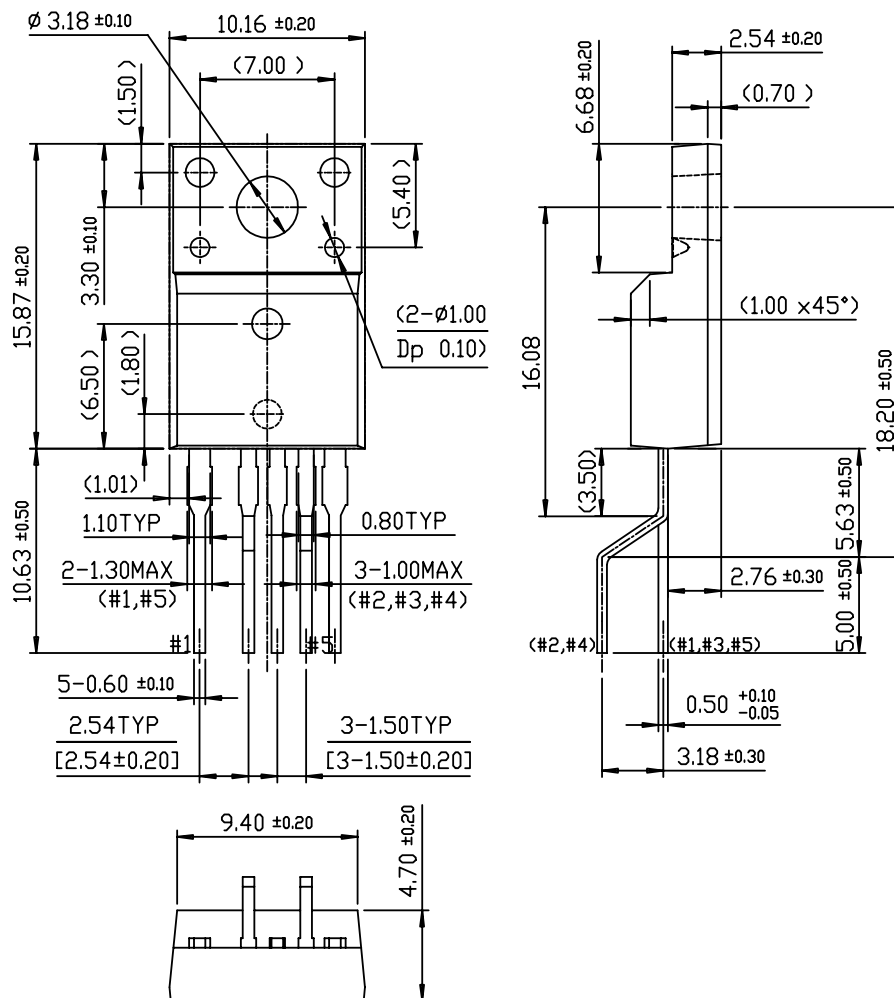
# Package Dimensions

## TO-220F-5L



Package Dimensions (Continued)

## TO-220F-5L(Forming)



## Ordering Information

Product Number	Package	Operating Temp.
KA5Q0740RTTU	TO-220F-5L	-25°C to +85°C
KA5Q0740RTYDTU	TO-220F-5L(Forming)	

TU : Non Forming Type

YDTU : Forming Type

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